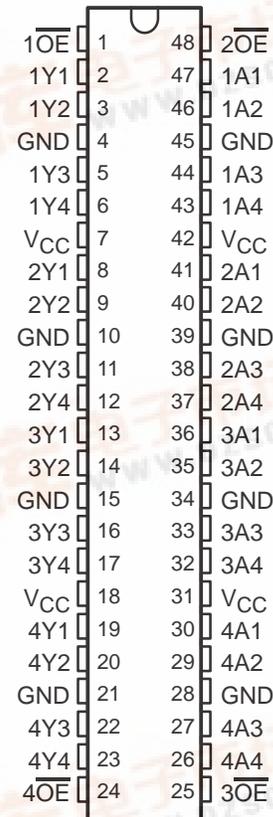


SN54AHCT16244, SN74AHCT16244 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCLS334I – MARCH 1996 – REVISED JANUARY 2000

- **Members of the Texas Instruments Widebus™ Family**
- **EPIC™ (Enhanced-Performance Implanted CMOS) Process**
- **Inputs Are TTL-Voltage Compatible**
- **Distributed V_{CC} and GND Pins Minimize High-Speed Switching Noise**
- **Flow-Through Architecture Optimizes PCB Layout**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015**
- **Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), and Thin Very Small-Outline (DGV) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings**

SN54AHCT16244 . . . WD PACKAGE
SN74AHCT16244 . . . DGG, DGV, OR DL PACKAGE
(TOP VIEW)



description

The 'AHCT16244 devices are 16-bit buffers and line drivers designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

These devices can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. They provide true outputs and symmetrical active-low output-enable (\overline{OE}) inputs.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHCT16244 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHCT16244 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE
(each 4-bit buffer/driver)

INPUTS		OUTPUT
\overline{OE}	A	Y
L	H	H
L	L	L
H	X	Z

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

EPIC and Widebus are trademarks of Texas Instruments Incorporated.

UNLESS OTHERWISE NOTED this document contains PRODUCTION DATA information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



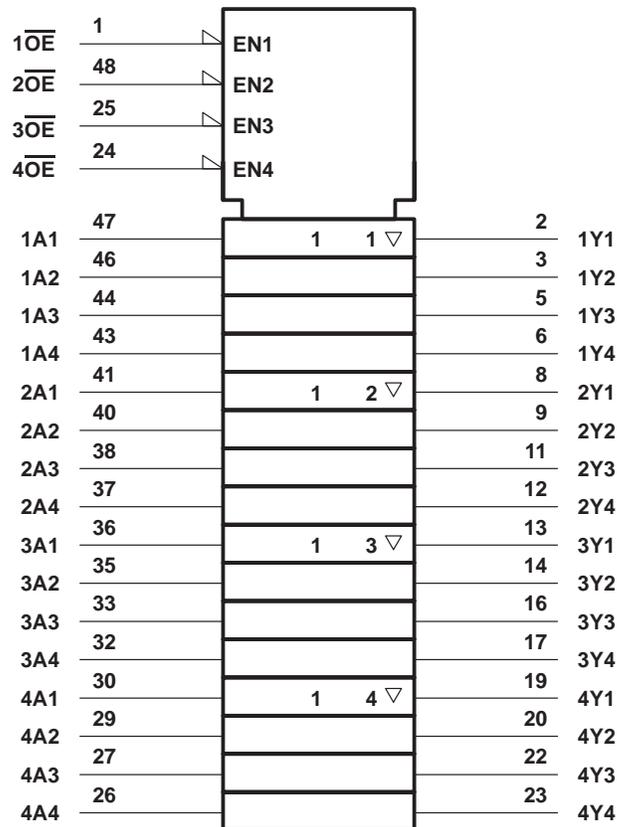
SN54AHCT16244, SN74AHCT16244

16-BIT BUFFERS/DRIVERS

WITH 3-STATE OUTPUTS

SCLS334I – MARCH 1996 – REVISED JANUARY 2000

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

SN54AHCT16244, SN74AHCT16244

16-BIT BUFFERS/DRIVERS

WITH 3-STATE OUTPUTS

SCLS3341 – MARCH 1996 – REVISED JANUARY 2000

recommended operating conditions (see Note 3)

	SN54AHCT16244		SN74AHCT16244		UNIT
	MIN	MAX	MIN	MAX	
V _{CC} Supply voltage	4.5	5.5	4.5	5.5	V
V _{IH} High-level input voltage	2		2		V
V _{IL} Low-level input voltage		0.8		0.8	V
V _I Input voltage	0	5.5	0	5.5	V
V _O Output voltage	0	V _{CC}	0	V _{CC}	V
I _{OH} High-level output current		-8		-8	mA
I _{OL} Low-level output current		8		8	mA
Δt/Δv Input transition rise or fall rate		20		20	ns/V
T _A Operating free-air temperature	-55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C			SN54AHCT16244		SN74AHCT16244		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V _{OH}	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		4.4	V	
	I _{OH} = -8 mA		3.94			3.8		3.8		
V _{OL}	I _{OL} = 50 μA	4.5 V			0.1			0.1	V	
	I _{OL} = 8 mA				0.36		0.44	0.44		
I _I	V _I = V _{CC} or GND	0 V to 5.5 V			±0.1		±1*	±1	μA	
I _{OZ}	V _O = V _{CC} or GND	5.5 V			±0.25		±2.5	±2.5	μA	
I _{CC}	V _I = V _{CC} or GND, I _O = 0	5.5 V			4		40	40	μA	
ΔI _{CC} †	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5	1.5	mA	
C _i	V _I = V _{CC} or GND	5 V		2.5	10			10	pF	
C _o	V _O = V _{CC} or GND	5 V		3					pF	

* On products compliant to MIL-PRF-38535, this parameter is not production tested at V_{CC} = 0 V.

† This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

SN54AHCT16244, SN74AHCT16244
16-BIT BUFFERS/DRIVERS
WITH 3-STATE OUTPUTS

SCLS334I – MARCH 1996 – REVISED JANUARY 2000

**switching characteristics over recommended operating free-air temperature range,
 $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN54AHCT16244		SN74AHCT16244		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	Y	$C_L = 15\text{ pF}$	5.4*	8.5*		1*	10*	1	9.5	ns
t_{PHL}				5.4*	8.5*	1*	10*	1	9.5		
t_{PZH}	\overline{OE}	Y	$C_L = 15\text{ pF}$	7.7*	10.4*		1*	12*	1	12	ns
t_{PZL}				7.7*	10.4*	1*	12*	1	12		
t_{PHZ}	\overline{OE}	Y	$C_L = 15\text{ pF}$	5*	10.4*		1*	12*	1	12	ns
t_{PLZ}				5*	10.4*	1*	12*	1	12		
t_{PLH}	A	Y	$C_L = 50\text{ pF}$	7	9.5		1	11	1	10.5	ns
t_{PHL}				5.9	9.5	1	11	1	10.5		
t_{PZH}	\overline{OE}	Y	$C_L = 50\text{ pF}$	8.2	11.4		1	13	1	13	ns
t_{PZL}				8.2	11.4	1	13	1	13		
t_{PHZ}	\overline{OE}	Y	$C_L = 50\text{ pF}$	8.8	11.4		1	13	1	13	ns
t_{PLZ}				8.8	11.4	1	13	1	13		
$t_{sk(o)}$			$C_L = 50\text{ pF}$			1**			1	ns	

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

** On products compliant to MIL-PRF-38535, this parameter does not apply.

noise characteristics, $V_{CC} = 5\text{ V}$, $C_L = 50\text{ pF}$, $T_A = 25^\circ\text{C}$ (see Note 4)

PARAMETER		SN74AHCT16244			UNIT
		MIN	TYP	MAX	
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}		0.7		V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}		-0.7		V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}		4.8		V
$V_{IH(D)}$	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V

NOTE 4: Characteristics are for surface-mount packages only.

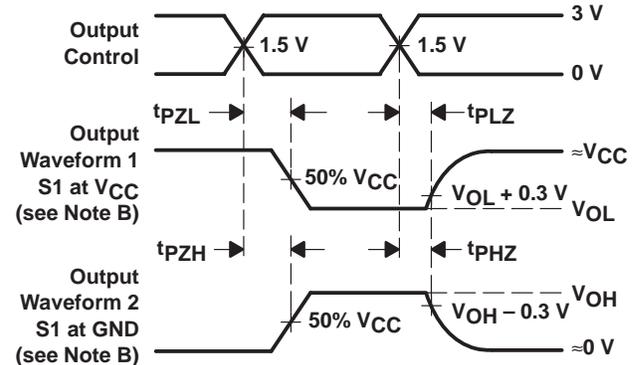
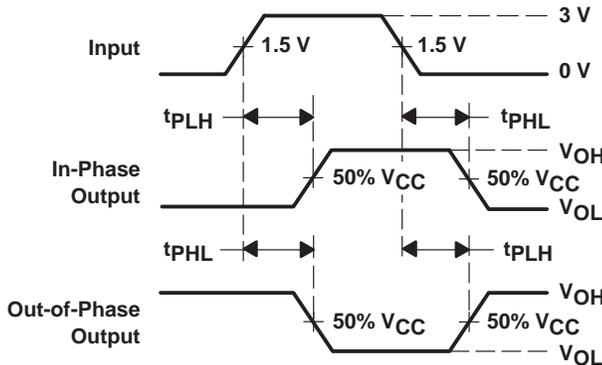
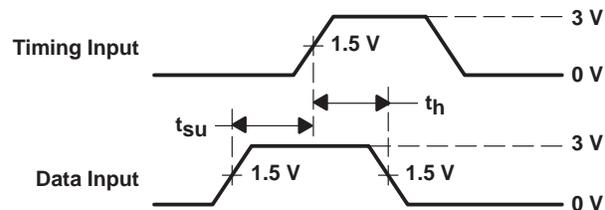
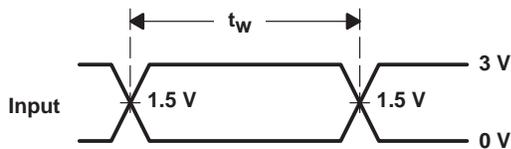
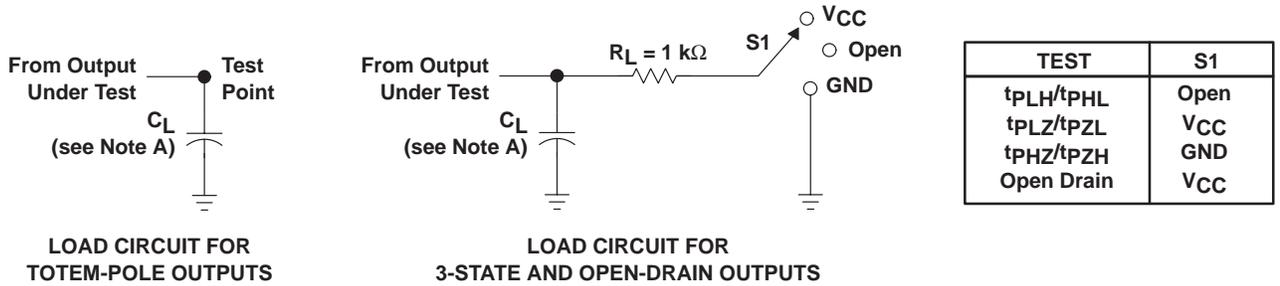
operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load, $f = 1\text{ MHz}$	8.2	pF

SN54AHCT16244, SN74AHCT16244 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCLS334I – MARCH 1996 – REVISED JANUARY 2000

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1$ MHz, $Z_O = 50 \Omega$, $t_r \leq 3$ ns, $t_f \leq 3$ ns.
 D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.